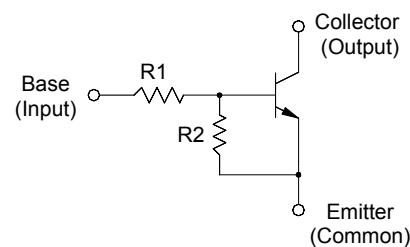




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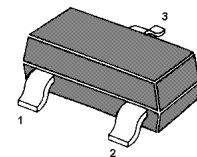
## MMBTRC107SS~MMBTRC109SS NPN Silicon Epitaxial Planar Transistor

for switching and interface circuit and  
drive circuit applications



### Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



1.Base 2.Emitter 3.Collector

SOT-23

### Resistor Values

Type	R1 (KΩ)	R2 (KΩ)	MARK
MMBTRC107SS	10	47	NH
MMBTRC108SS	22	47	NI
MMBTRC109SS	47	22	NJ

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Output Voltage	$V_O$	50	V
Input Voltage	$V_I$	30, -6	V
		40, -7	
		40, -15	
Output Current	$I_O$	100	mA
Total Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_s$	- 55 to + 150	°C



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**Characteristics at  $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_O = 5 \text{ V}$ , $I_O = 10 \text{ mA}$	$G_I$	80	-	-	-
		80	-	-	-
		70	-	-	-
Output Cutoff Current at $V_O = 50 \text{ V}$	$I_{O(OFF)}$	-	-	500	nA
Input Current at $V_I = 5 \text{ V}$	$I_I$	-	-	0.88	mA
		-	-	0.36	
		-	-	0.16	
Output Voltage at $I_O = 10 \text{ mA}$ , $I_I = 0.5 \text{ mA}$	$V_{O(ON)}$	-	-	0.3	V
Input Voltage (ON) at $V_O = 0.2 \text{ V}$ , $I_O = 5 \text{ mA}$	$V_{I(ON)}$	-	-	1.8	V
		-	-	2.6	
		-	-	5.8	
Input Voltage (OFF) at $V_O = 5 \text{ V}$ , $I_O = 0.1 \text{ mA}$	$V_{I(OFF)}$	0.5	-	-	V
		0.6	-	-	
		1.5	-	-	
Transition Frequency at $V_O = 10 \text{ V}$ , $I_O = 5 \text{ mA}$	$f_T^{(1)}$	-	200	-	MHz

1) Characteristic of transistor only.

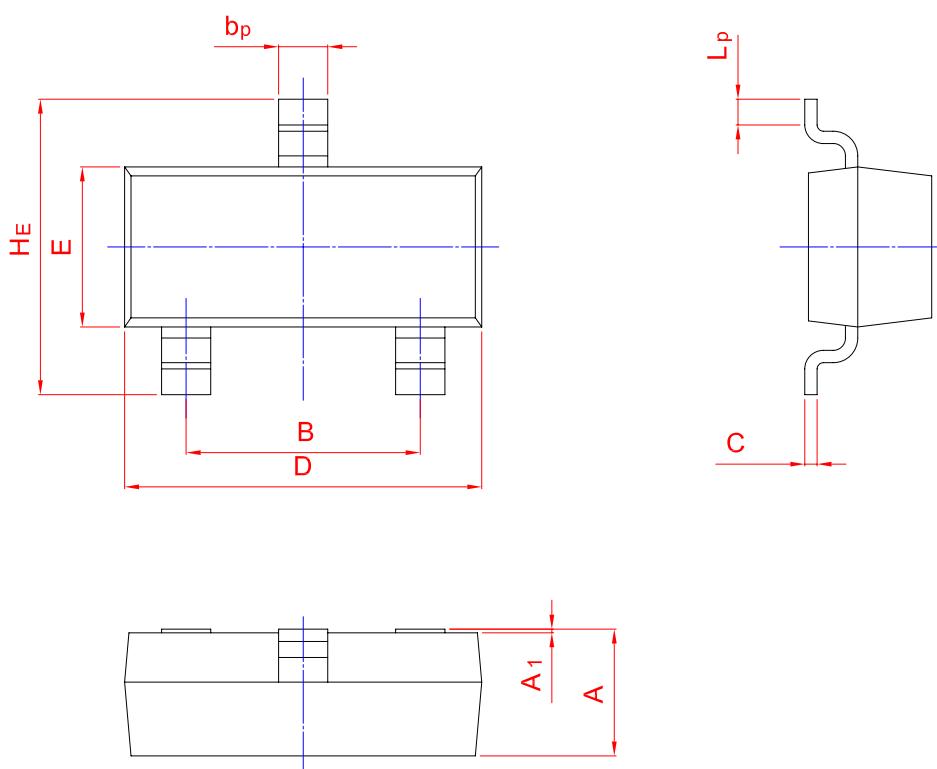


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## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

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UNIT	A	B	b <sub>p</sub>	C	D	E	H <sub>E</sub>	A <sub>1</sub>	L <sub>p</sub>
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20